

4V Drive Nch MOSFET

RP1L055SN

● Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (MPT6).

● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	1000
RP1L055SN	O	

● Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Drain-source voltage	V_{DSS}	60	V
Gate-source voltage	V_{GSS}	± 20	V
Drain current	Continuous	I_D	A
	Pulsed	I_{DP} *1	A
(Body Diode)	Continuous	I_S	A
	Pulsed	I_{SP} *1	A
Power dissipation	P_D *2	2.0	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Range of storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

*1 $P_w \leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

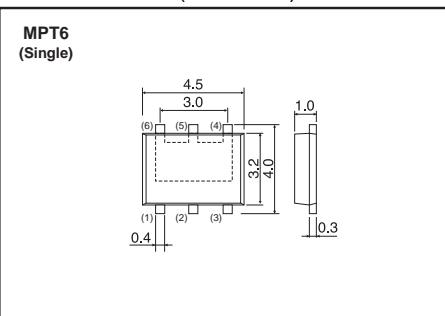
*2 Mounted on a ceramic board.

● Thermal resistance

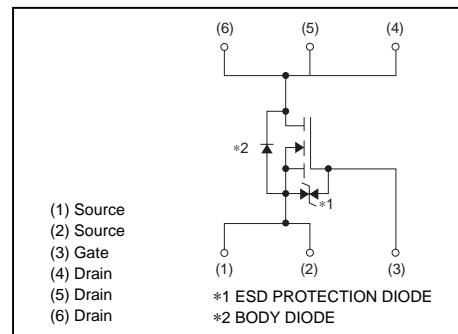
Parameter	Symbol	Limits	Unit
Channel to Ambient	$R_{th (ch-a)}$ *	62.5	$^\circ\text{C} / \text{W}$

*Mounted on a ceramic board.

● Dimensions (Unit : mm)



● Inner circuit



●Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	± 10	μA	$V_{GS}=\pm 20\text{V}, V_{DS}=0\text{V}$
Drain-source breakdown voltage	$V_{(BR)DSS}$	60	-	-	V	$I_D=1\text{mA}, V_{GS}=0\text{V}$
Zero gate voltage drain current	I_{DSS}	-	-	1	μA	$V_{DS}=60\text{V}, V_{GS}=0\text{V}$
Gate threshold voltage	$V_{GS(\text{th})}$	1.0	-	3.0	V	$V_{DS}=10\text{V}, I_D=1\text{mA}$
Static drain-source on-state resistance	$R_{DS(\text{on})}^*$	-	35	49	$\text{m}\Omega$	$I_D=5.5\text{A}, V_{GS}=10\text{V}$
		-	40	56		$I_D=5.5\text{A}, V_{GS}=4.5\text{V}$
		-	45	63		$I_D=5.5\text{A}, V_{GS}=4.0\text{V}$
Forward transfer admittance	$ Y_{fs} ^*$	5.0	-	-	S	$I_D=5.5\text{A}, V_{DS}=10\text{V}$
Input capacitance	C_{iss}	-	730	-	pF	$V_{DS}=10\text{V}$
Output capacitance	C_{oss}	-	180	-	pF	$V_{GS}=0\text{V}$
Reverse transfer capacitance	C_{rss}	-	70	-	pF	$f=1\text{MHz}$
Turn-on delay time	$t_{d(on)}^*$	-	12	-	ns	$I_D=2.75\text{A}, V_{DD}=30\text{V}$
Rise time	t_r^*	-	14	-	ns	$V_{GS}=10\text{V}$
Turn-off delay time	$t_{d(off)}^*$	-	40	-	ns	$R_L=10.9\Omega$
Fall time	t_f^*	-	10	-	ns	$R_G=10\Omega$
Total gate charge	Q_g^*	-	14	-	nC	$I_D=5.5\text{A}, V_{DD}=30\text{V}$
Gate-source charge	Q_{gs}^*	-	2.5	-	nC	$V_{GS}=10\text{V}$
Gate-drain charge	Q_{gd}^*	-	3.0	-	nC	

*Pulsed

●Body diode characteristics (Source-Drain) ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD}^*	-	-	1.2	V	$I_s=5.5\text{A}, V_{GS}=0\text{V}$

*Pulsed

● Electrical characteristic curves ($T_a=25^\circ\text{C}$)

Fig.1 Typical Output Characteristics (I)

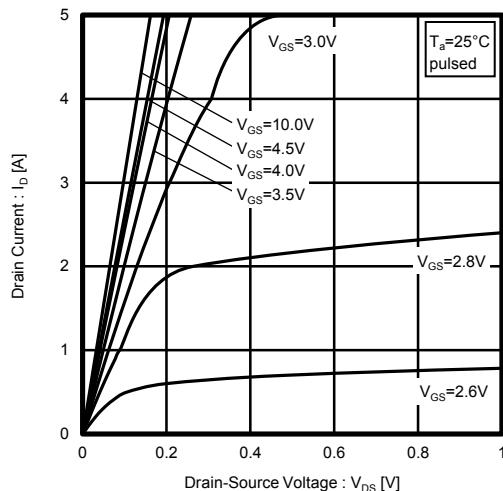


Fig.2 Typical Output Characteristics (II)

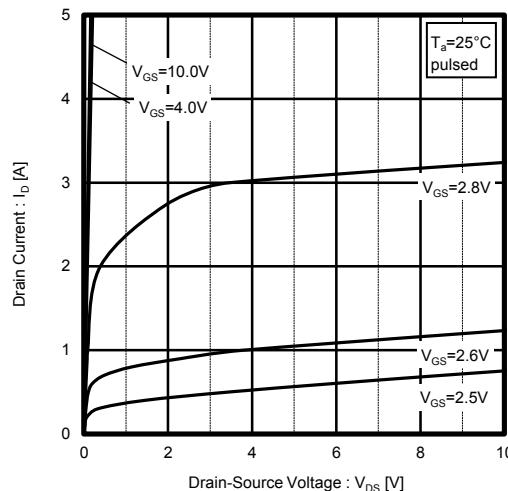


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

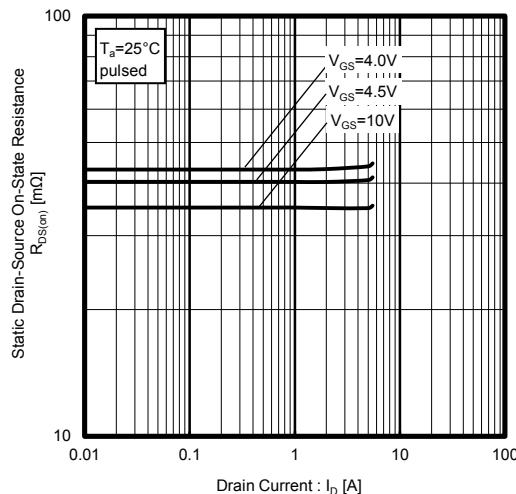


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

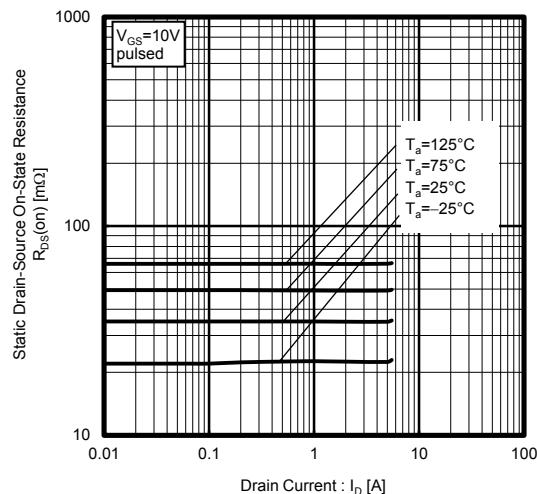


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

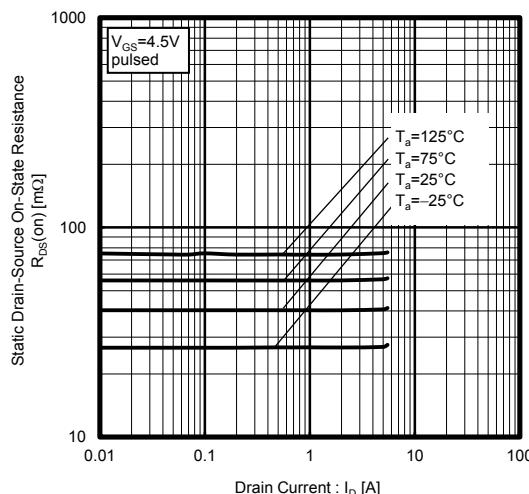


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current

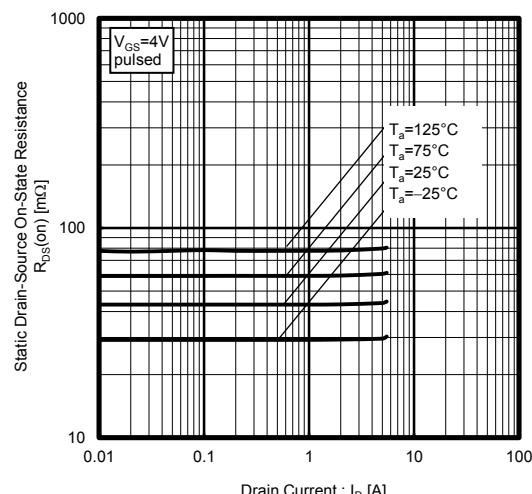


Fig.7 Forward Transfer Admittance vs. Drain Current

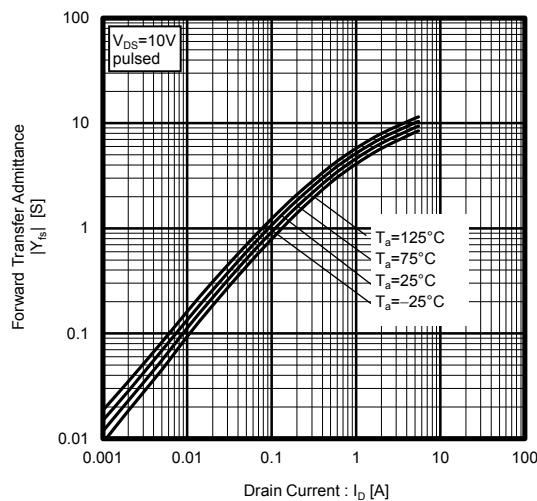


Fig.8 Typical Transfer Characteristics

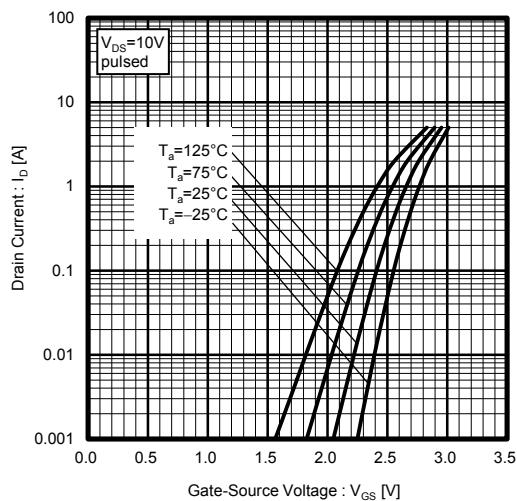


Fig.9 Source Current vs. Source-Drain Voltage

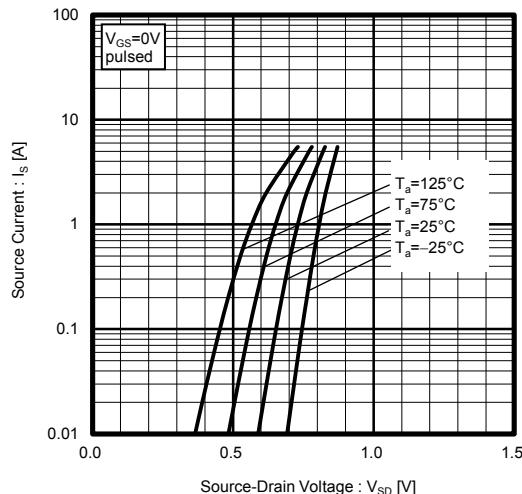


Fig.10 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

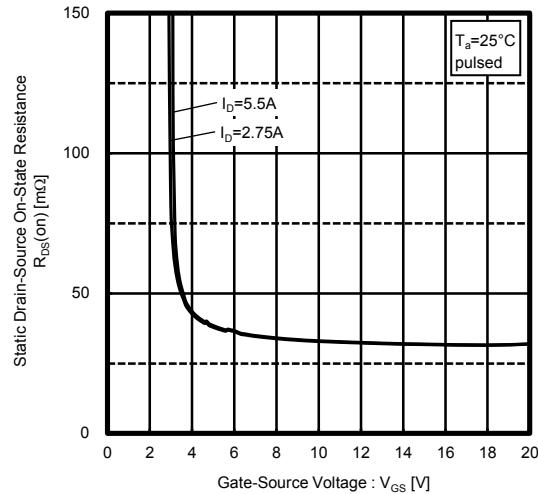


Fig.11 Switching Characteristics

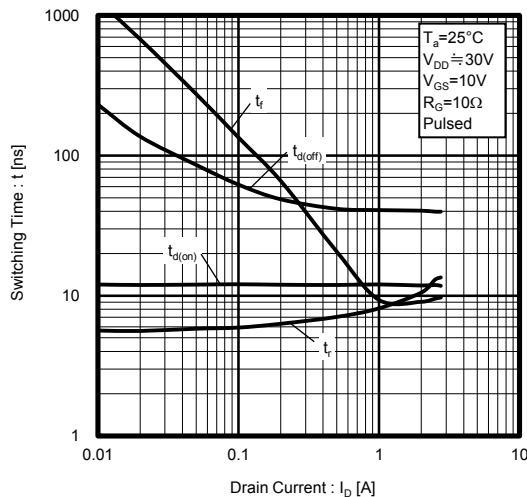


Fig.12 Dynamic Input Characteristics

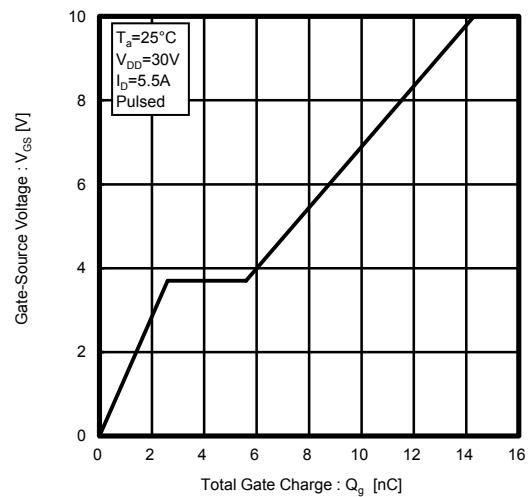


Fig.13 Typical Capacitance vs. Drain-Source Voltage

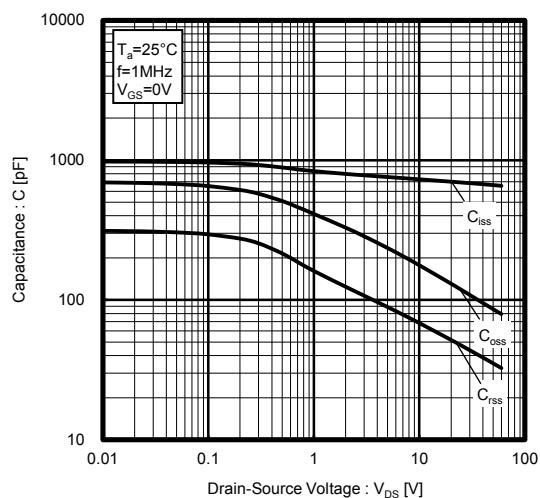


Fig.14 Maximum Safe Operating Area

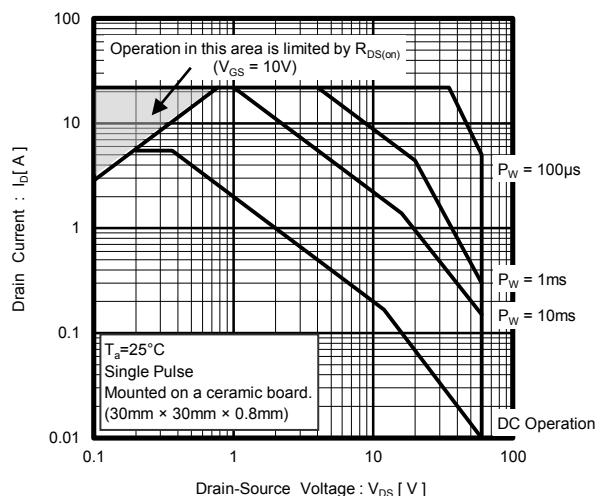
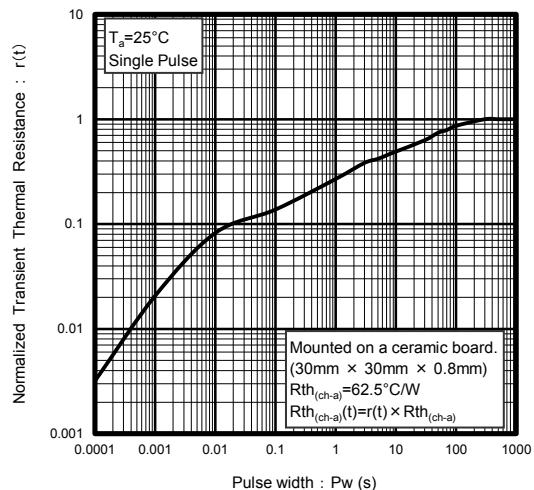


Fig.15 Normalized Transient Thermal Resistance v.s. Pulse Width



● Measurement circuits

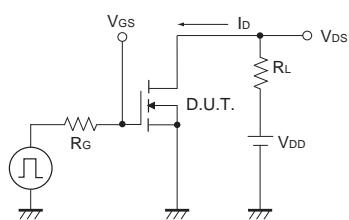


Fig.1-1 Switching Time Measurement Circuit

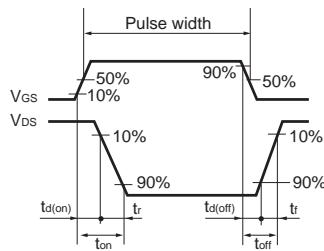


Fig.1-2 Switching Waveforms

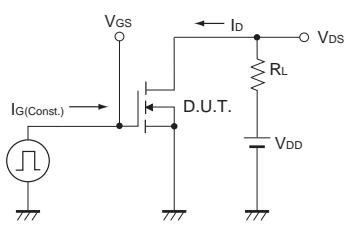


Fig.2-1 Gate Charge Measurement Circuit

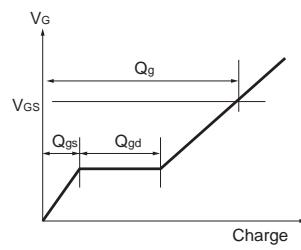


Fig.2-2 Gate Charge Waveform

Notes

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